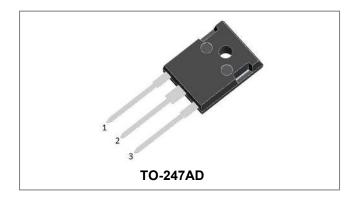


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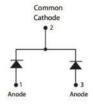
# **MBR30100WT SCHOTTKY RECTIFIER**



### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

### **Maximum Ratings:**

| Characteristics                                                                        | Symbol                                           | Condition                                                        | Max.                          | Units |
|----------------------------------------------------------------------------------------|--------------------------------------------------|------------------------------------------------------------------|-------------------------------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$ | -                                                                | 100                           | V     |
| Average Rectified Forward Current                                                      | I <sub>F (AV)</sub>                              | 50% duty cycle @Tc=103°C, rectangular wave form                  | 15(Per Leg)<br>30(Per Device) | А     |
| Peak Repetitive Forward Current(Per Leg)                                               | I <sub>FRM</sub>                                 | Rated V <sub>R</sub> square wave,<br>20KHz T <sub>C</sub> =133°C | 20                            | Α     |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg)                                   | I <sub>FSM</sub>                                 | 8.3ms, Half Sine pulse                                           | 150                           | Α     |

## **Electrical Characteristics:**

| Characteristics                 | Symbol          | Condition                                                                        | Тур.         | Max.         | Units |
|---------------------------------|-----------------|----------------------------------------------------------------------------------|--------------|--------------|-------|
| Forward Voltage Drop (per leg)* | V <sub>F1</sub> | @ 15A, Pulse, T <sub>J</sub> = 25 °C<br>@ 30 A, Pulse, T <sub>J</sub> = 25 °C    | 0.78<br>0.90 | 0.85<br>1.05 | V     |
|                                 | $V_{F2}$        | @ 15 A, Pulse, T <sub>J</sub> = 125 °C<br>@ 30 A, Pulse, T <sub>J</sub> = 125 °C | 0.65<br>0.77 | 0.70<br>0.85 | V     |
| Reverse Current (per leg) *     | I <sub>R1</sub> | @V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C                  | 0.003        | 1.0          | mA    |
|                                 | I <sub>R2</sub> | @V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C                 | 2            | 15.0         | mA    |
| Junction Capacitance (per leg)  | Ст              | $@V_R = 5V, T_C = 25 ^{\circ}C$<br>$f_{SIG} = 1MHz$                              | 380          | 500          | pF    |
| Voltage Rate of Change          | dv/dt           | -                                                                                | -            | 10,000       | V/μs  |

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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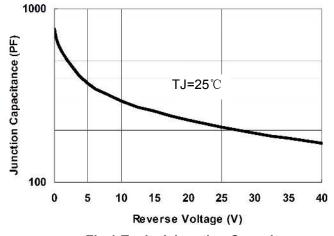




# **Thermal-Mechanical Specifications:**

| Characteristics                                  | Symbol           | Condition                            | Specification | Units |
|--------------------------------------------------|------------------|--------------------------------------|---------------|-------|
| Junction Temperature                             | TJ               | -                                    | -55 to +150   | °C    |
| Storage Temperature                              | T <sub>stg</sub> | -                                    | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Case      | R <sub>θJC</sub> | DC operation                         | 2.0           | °C/W  |
| Typical Thermal Resistance, Case to Heat Sink    | $R_{	heta JA}$   | DC operation                         | 50            | °C/W  |
| Typical Thermal<br>Resistance, Case to Heat Sink | R <sub>θCS</sub> | Mounting surface, smooth and greased | 0.50          | °C/W  |
| Approximate Weight                               | wt               | -                                    | 6.28          | g     |
| Case Style                                       | TO-247AD         |                                      |               |       |

## **Ratings and Characteristics Curves**



**Fig.1-Typical Junction Capacitance** 

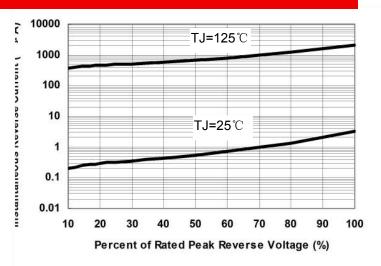


Fig.2-Typical Reverse Characteristics

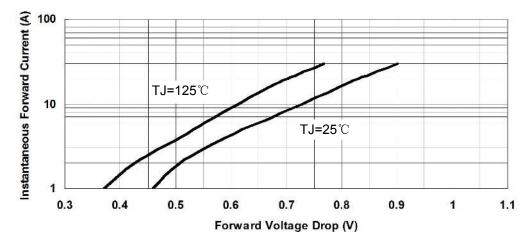


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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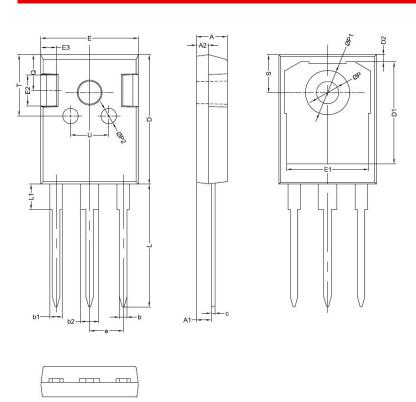


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## **Mechanical Dimensions TO-247AD**



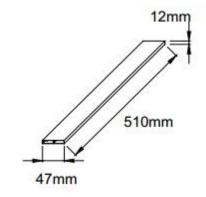
| SYMBOL      | Millimeters |       |       |  |  |  |
|-------------|-------------|-------|-------|--|--|--|
|             | MIN.        | TYP.  | MAX.  |  |  |  |
| Α           | 4.80        | 5.00  | 5.20  |  |  |  |
| A1          | 2.20        | 2.41  | 2.61  |  |  |  |
| A2          | 1.90        | 2.00  | 2.10  |  |  |  |
| Ь           | 1.10        | 1.20  | 1.40  |  |  |  |
| b1          | 1.80        | 2.00  | 2.20  |  |  |  |
| b2          | 2.80        | 3.00  | 3.20  |  |  |  |
| С           | 0.50        | 0.60  | 0.75  |  |  |  |
| D           | 20.30       | 21.00 | 21.20 |  |  |  |
| D1          |             | 16.55 |       |  |  |  |
| D2<br>E     |             | 1.20  |       |  |  |  |
| Ш           | 15.45       | 15.80 | 16.00 |  |  |  |
| E1          |             | 13.30 |       |  |  |  |
| E2          |             | 5.00  |       |  |  |  |
| E3          |             | 2.50  |       |  |  |  |
| е           |             | 5.44  |       |  |  |  |
| L           | 19.42       | 19.92 | 20.70 |  |  |  |
| L1          |             | 4.13  |       |  |  |  |
| Р           | 3.50        | 3.60  | 3.70  |  |  |  |
| P1          | 7.1         |       | 7.40  |  |  |  |
| P2          |             | 2.50  |       |  |  |  |
|             |             | 5.80  |       |  |  |  |
| Q<br>S<br>T | 6.05        | 6.15  | 6.25  |  |  |  |
| T           |             | 10.00 |       |  |  |  |
| U           |             | 6.20  |       |  |  |  |

# **Ordering Information:**

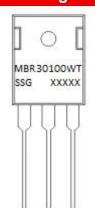
| Device     | Package           | Shipping     |  |
|------------|-------------------|--------------|--|
| MBR30100WT | TO-247AD(Pb-Free) | 25pcs / tube |  |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 30 = Forward Current (30A) 100 = Reverse Voltage (100V) WT = Configuration SSG = SSG

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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#### **MBR30100WT**



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